



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of:

Geum-Jong BAE, et al

Art Unit: 2814

Serial No. 10/659,384
(Division of Serial No. 10/274,035)

Examiner: Hoai V. Pham

Filed: September 11, 2003

Confirmation No. 3795

For: MOS TRANSISTOR HAVING A T-SHAPED
GATE ELECTRODE AND METHOD FOR
FABRICATING THE SAME

Attorney Docket No. 239/169 DIV

AMENDMENT UNDER 37 C.F.R. § 1.111

Mail Stop: Amendments
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

INTRODUCTORY COMMENTS

In response to the Office action dated April 20, 2006, the following amendments and remarks are respectfully submitted in connection with the above-identified application:

Amendments to the Claims are reflected in a listing of the claims, begins on page 2 of this paper.

Remarks begin on page 6 of this paper.